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## ■ ABSOLUTE MAXIMUM RATINGS

( Ta=25℃ )

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V <sub>DD</sub> - V <sub>EE</sub>	- 0.5 ~ + 20	٧
Input Voltage(Control Signal)	VIN	$V_{ss}-0.5 \sim V_{DD}+0.5$	V
Input Voltage(Analog Signal)	Vsig	$V_{\text{EE}}$ -0.5 ~ $V_{\text{DD}}$ +0.5	V
Input Current	l in	± 10	mA
Output Current	Ιουτ	± 10	mA
Power Dissipation	Po	500 (DIP) 200 (DMP) 300 (SSOP)	mW
Operating Temperature Range	Topr	- 40 ~ + 85	°C
Storage Temperature Range	Tstg	- 65 ~ + 150	°C

## ELECTRICAL CHARACTERISTICS

• DC Characteristics

PARAMETER S	OVUDO	CONDITIONS		$V_{\text{DD}}$	Ta=-40℃ Ta=25℃		C	Ta=8	Ta=85℃	
	SYMBOL			(V)	MIN MAX	MIN TYP	MAX	MIN	MAX	UNIT
Quiescent Current	סס	No signal Per Package		5 10 15 20	5 10 20 100		5 10 20 100		150 300 600 3000	μA
On-State Resistance	Ron	0≦Vis≦Vdd VEE=VSS=0V		5 10 15	500 210 140	220 100 60			800 300 200	Ω
On-State Resistance Deviation	$\Delta R_{\text{on}}$	Between 2 channels V <sub>EE</sub> =V <sub>SS</sub> =0V		5 10 15		15 10 5				Ω
Off-Channel Leakage Current		Each channel V <sub>EE</sub> =V <i>ss</i> =0V		18	±1000	±10	±100	=	<b>±</b> 1000	nA
Input Capacitance	Сти	Vı№=OV Control Inhibit Switch				5.0 10	7.5			pF
Low Level Input Voltage	Vil	R⊾=10kΩ S₩=V⊳⊳	Vo=1.0V Vo=1.0V Vo=1.5V	5 10 15	1.5 3.0 4.0		1.5 3.0 4.0		1.5 3.0 4.0	V
High Level Input Voltage	Vih	Vee=Vss	Vo=4.0V Vo=9.0V Vo=13.5V	5 10 15	3.5 7.0 11.0	3.5 7.0 11.0		3.5 7.0 11.0		۷
Input Current	±11N	V <sub>IN</sub> =0 or 18V		18	±0.1		±0.1		± 1	μA

(Vss=0V)

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## SWITCHING CHARACTERISTICS

( Ta=25°C, CL=50pF )

PARAN	<u>IETER</u>	SYMBOL	CONDITIONS	$V_{DD}(V)$	MIN TYP MAX	UNIT
Propagation Delay Time	SW Input to Output	tPLH		5 10 15	15 45 8 30 5 20	
		tphl	R⊥=10kΩ	5 10 15	15 45 8 30 5 20	ns
	CONT Input to Output	tphl		5 10 15	450 1000 200 500 150 400	ns
		tpzh tpzl		5 10 15	450 1000 200 500 150 400	115
Output Enable Time		t <sub>PHZ</sub>	R <sub>1</sub> =10kΩ	5 10 15	600 1400 250 700 200 500	ns
Output Disable Time			112 10132	5 10 15	600 1400 250 700 200 500	ns
Sine-Wave Distortion			$R_{\rm L}\text{=}10k\Omega$ , f=1kHz, $V_{\rm IS}\text{=}5V_{\rm P-P}$	10	0.05	%
Feedthrough (all-ch. off)			$R_{L}=1k\Omega$ , 20 $\log_{10}V_{os}/V_{1S}=-50dB$	10	4.5	MHz
Crosstalk	SW A to B		$R_L=1k\Omega$ , $V_{1S}=1/2(V_{DD}-V_{SS})_{P-P}$	10	3.0	MHz
or ood turk	Control-Out		$R_1=1k\Omega$ , $R_L=10k\Omega$ , tr=tf=20ns CONTROL/INHIBIT	10	30	mV

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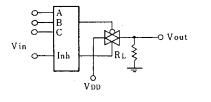
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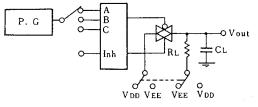
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## MEASUREMENT CIRCUITS

1. Noise Margin

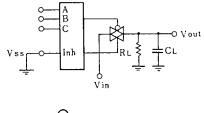
2. Propagation Delay



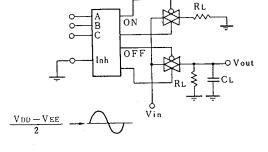


3. Feedthrough

4. Crosstalk (Switch A and B)

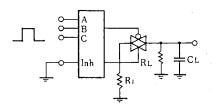






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5. Crosstalk (Control and Out)



**MEMO** 

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